DS04-28207-2E

ASSP for Image Processing

CMOS

A/D Converter (1-channel, 8-bit, 20MHz)

MB40C568

■ DESCRIPTION

The MB40C568 is a high-speed A/D converter using high-speed CMOS process technology.

■ FEATURES

· Resolution: 8 bits

• Linearity error: ±0.20% (Typ.)

Maximum conversion rate: 20 MSPS (Min.)

• Power supply voltage: Analog section +5.0 V

Digital section +3.0 V or +5.0 V

• Digital input voltage range: TTL level

• Digital output voltage range: CMOS level compatible

Analog input voltage range: 0.5 to 4 V (with 2 Vp-p)

• Analog input capacity: 15 pF (Typ.)

• Power consumption: 50 mW (Typical:@fclk = 20 MHz, AVDD = 5 V, DVDD = 3 V)

60 mW (Typical: @fclk = 20 MHz, AVDD = DVDD = 5 V)

Additional function: Reference voltage generator circuit: VREFT = 3 V, VREFB = 1 V

• Package options: SOP24, SSOP24

■ PACKAGES

24-pin, Plastic SSOP

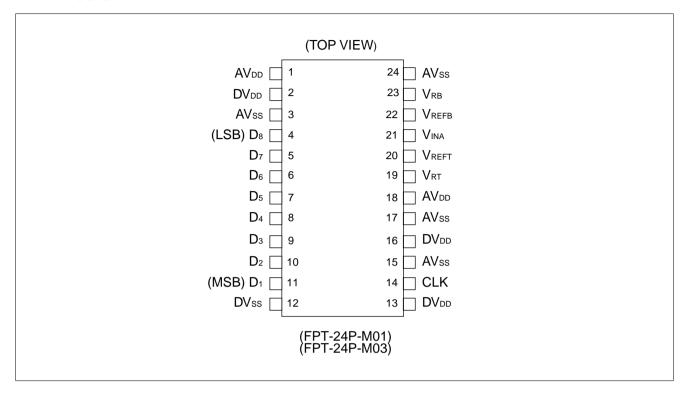
24-pin, Plastic SSOP

(FPT-24P-M01)

(FPT-24P-M03)

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Pin name	Functions
1, 18	AV _{DD}	Analog power supply pins (+5 V)
2, 13, 16	DV _{DD}	Digital power supply pins (+3 or +5 V)
3, 15, 17, 24	AVss	Analog power ground pins (0 V)
12	DVss	Digital power ground pin (0 V)
4 to 11	D ₁ to D ₈	Digital output pins. D ₁ : MSB, D ₈ : LSB
14	CLK	Clock input pin
21	VINA	Analog input pin. Input range: VRB to VRT (2 Vp-p between 0.5 to 4 V)
19	V _{RT}	Reference voltage input pin (3 V)
20	VREFT	Reference voltage output pin. When connected to V_{RT} , the pin generates $0.6 \times AV_{DD}$ (3 V).
23	V _{RB}	Reference voltage input pin (1 V)
22	VREFB	Reference voltage output pin. When connected to V_{RB} , the pin generates $0.2 \times AV_{DD}$ (1 V).

Values within () are typical values.

■ NOTES ON USE

- Be sure to bypass the AV_{DD}, DV_{DD}, V_{RT} and V_{RB} pins to the ground using a high-frequency capacitor. The high-frequency capacitor should be connected as near the pin as possible.
- Provide four clocks or more immediately after the power up to prevent current dissipation due to the indeterminate internal logic.

MB40C568

■ ABSOLUTE MAXIMUM RATINGS (See WARNING)

Parameter	Symbol	Rat	Unit	
Parameter	Symbol	Min.	Max.	Unit
Power supply voltage	AV _{DD} , DV _{DD}	-0.3	7.0	V
Input voltage	CLK, VINA VRT, VRB	-0.3	AVDD+0.3	V
Output voltage	D ₁ to D ₈	-0.3	DV _{DD} +0.3	V
Storage temperature	Tstg	- 55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Unit		
Farameter	Syllibol	Min.	Тур.	Max.	Onit
Analog input voltage	VINA	V _{RB}	_	V _{RT}	V
Analog reference voltage: T	V _{RT}	_	_	4.00	V
Analog reference voltage: B	V_{RB}	0.50	_	_	V
Analog reference voltage range	V _{RT} –V _{RB}	1.90	2.00	2.10	V
Digital "H" level input voltage	VIHD	2.4	_	_	V
Digital "L" level input voltage	VILD	_	_	0.8	V
Digital input current	IID	_	_	5	μΑ
Clock frequency	fськ	0.1	_	20	MHz
Minimum "H" level clock pulse width	tw+	22.5	_	_	ns
Minimum "L" level clock pulse width	tw-	22.5	_	_	ns
Operating temperature range	Та	-20	_	70	°C

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

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• When using a single power supply

Parameter	Symbol		Value		Unit	
Farameter	Syllibol	Min.	Тур.	Max.	Offic	
Power supply voltage	AV _{DD} , DV _{DD}	4.75	5.00	5.25	V	

• When using dual power supplies

Parameter	Symbol		Unit		
r ai ailletei	Symbol	Min.	Тур.	Max.	Offic
Power supply voltage	AVDD	4.75	5.00	5.25	V
Power supply voltage	DV _{DD}	2.70	3.00	3.30	V

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

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■ ELECTRICAL CHARACTERISTICS (Using a Single Power Supply)

DC Characteristics

(1) Analog section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol			Unit	
raidilletei	raiainetei		Min.	Тур.	Max.	Oilit
Resolution		_	_	8	_	bit
Linearity error	DC precision	LE	_	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity	Analog input capacity		_	15	_	pF
Reference voltage: T		VREFT	_	0.6 × AV _{DD}	_	V
Reference voltage: B		VREFB	_	0.2 × AV _{DD}	_	V
Reference current		lпв	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	_	8.0	14.0	mA
Digital power supply current		DI _{DD}	_	4.0	7.0	mA

(2) Digital section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	4.2	_	DV _{DD}	V
Digital "L" level output voltage	Vold	_	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	Іоь	_	_	1.6	mA

(3) Switching section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
r ai ailletei	Symbol	Min.	Тур.	Max.	Offic
Maximum conversion rate	fs	20	_	_	MSPS
Digital output delay time	tpd	0	5	20	ns

■ ELECTRICAL CHARACTERISTICS (Using Dual Power Supplies)

DC Characteristics

(1) Analog section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol			Unit	
raiailletei	raraineter		Min.	Тур.	Max.	Onit
Resolution		_	-	8	_	bit
Linearity error	DC precision	LE	_	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity	Analog input capacity		_	15	_	pF
Reference voltage: T		VREFT	_	0.6 × AVDD	_	V
Reference voltage: B		VREFB	_	0.2 × AV _{DD}	_	V
Reference current		lпв	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	_	8.0	14.0	mA
Digital power supply current		DIDD	_	3.0	5.0	mA

(2) Digital section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	2.4	_	DV _{DD}	V
Digital "L" level output voltage	Vold	_	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	Іоь	_	_	1.6	mA

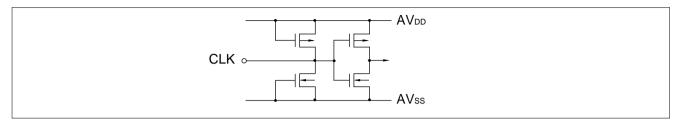
(3) Switching section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

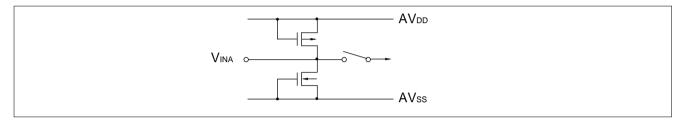
Parameter	Symbol		Unit		
r ai ailletei	Symbol	Min.	Тур.	Max.	Offic
Maximum conversion rate	fs	20	_	_	MSPS
Digital output delay time	tpd	0	6	25	ns

■ EQUIVALENT CIRCUIT

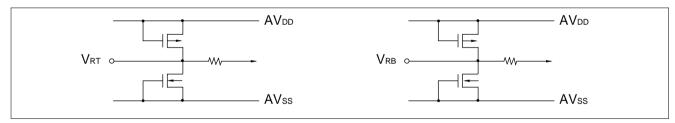
• Clock input



Analog input



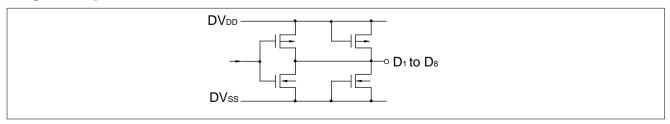
• Reference voltage input



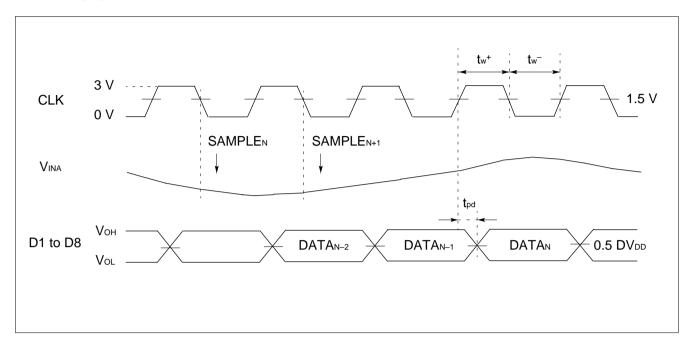
• Reference voltage output



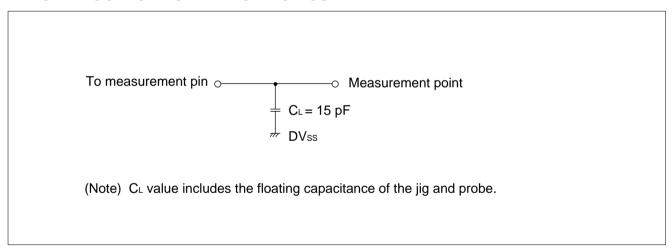
Digital output



■ TIMING CHART



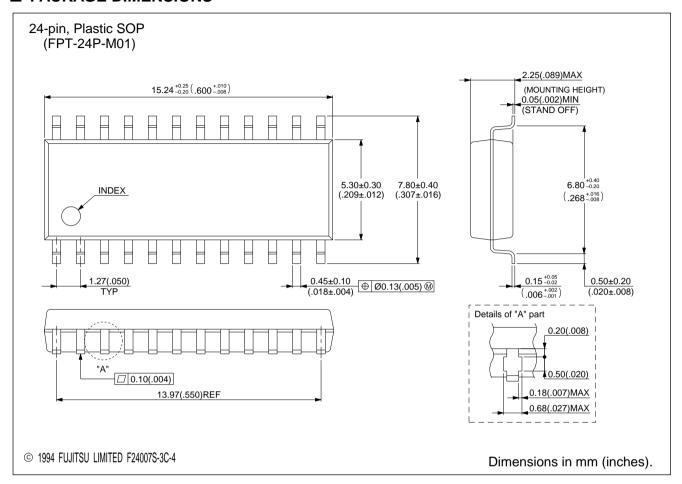
■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



■ ORDERING INFORMATION

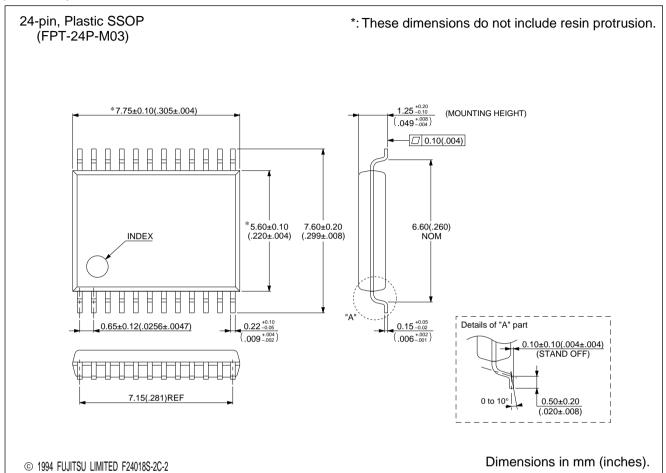
Part number	Package	Remarks
MB40C568PF	24-pin, Plastic SOP (FPT-24P-M01)	
MB40C568PFV	24-pin, Plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSIONS



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FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED Corporate Global Business Support Division Electronic Devices KAWASAKI PLANT, 4-1-1, Kamikodanaka Nakahara-ku, Kawasaki-shi Kanagawa 211-88, Japan

Tel: (044) 754-3763 Fax: (044) 754-3329

North and South America

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, U.S.A. Tel: (408) 922-9000

Fax: (408) 432-9044/9045

Europe

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10 63303 Dreieich-Buchschlag Germany

Tel: (06103) 690-0 Fax: (06103) 690-122

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE. LIMITED #05-08, 151 Lorong Chuan
New Tech Park

Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220 All Rights Reserved.

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